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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# Infrarot-LED Infrared-LED

## SFH 4281



### Wesentliche Merkmale

- Emissionswellenlänge 880nm
- Homogene Abstrahlcharakteristik
- IR Reflow und TTW Löten geeignet
- Feuchte-Empfindlichkeitsstufe 2 nach JEDEC Standard J-STD-020A

### Anwendungen

- Miniaturlichtschranken für Gleich- und Wechsellichtbetrieb
- Industrieelektronik
- „Messen/Steuern/Regeln“
- Automobiltechnik
- Sensorik
- Alarm- und Sicherungssysteme
- IR-Freiraumübertragung

### Features

- Typical peak wavelength 880nm
- Homogeneous Radiation Pattern
- Suitable for IR reflow and TTW soldering
- Moisture Sensitivity Level 2 according to JEDEC Standard J-STD-020A

### Applications

- Miniature photointerrupters
- Industrial electronics
- For drive and control circuits
- Automotive technology
- Sensor technology
- Alarm and safety equipment
- IR free air transmission

Typ Type	Bestellnummer Ordering Code	Strahlstärkegruppierung <sup>1)</sup> ( $I_F = 100 \text{ mA}$ , $t_p = 20 \text{ ms}$ ) Radiant intensity grouping <sup>1)</sup> , $I_e$ (mW/sr)	
		-P	-Q
SFH 4281	Q62702P5000	4 ... 8	6.3 ... 12.5

<sup>1)</sup> gemessen bei einem Raumwinkel  $\Omega = 0.01 \text{ sr}$  / measured at a solid angle of  $\Omega = 0.01 \text{ sr}$

**Grenzwerte ( $T_A = 25^\circ\text{C}$ )****Maximum Ratings**

<b>Bezeichnung Parameter</b>	<b>Symbol Symbol</b>	<b>Wert Value</b>	<b>Einheit Unit</b>
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{\text{op}}; T_{\text{stg}}$	-40 ... +100	°C
Sperrspannung Reverse voltage	$V_R$	5	V
Durchlaßstrom Forward current	$I_F$	100	mA
Stoßstrom, $\tau = 10 \mu\text{s}, D = 0$ Surge current	$I_{\text{FSM}}$	2.5	A
Verlustleistung Power dissipation	$P_{\text{tot}}$	180	mW
Wärmewiderstand Sperrsicht - Umgebung bei Montage auf FR4 Platine, Padgröße je 16 mm <sup>2</sup> Thermal resistance junction - ambient mounted on PC-board (FR4), pads size 16 mm <sup>2</sup> each	$R_{\text{thJA}}$	450	K/W
Wärmewiderstand Sperrsicht - Lötstelle bei Montage auf Metall-Block Thermal resistance junction - soldering point, mounted on metal block	$R_{\text{thJC}}$	≈ 200	K/W

**Kennwerte ( $T_A = 25^\circ\text{C}$ )****Characteristics**

<b>Bezeichnung Parameter</b>	<b>Symbol Symbol</b>	<b>Wert Value</b>	<b>Einheit Unit</b>
Wellenlänge der Strahlung Wavelength at peak emission $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$\lambda_{\text{peak}}$	880	nm
Spektrale Bandbreite bei 50% von $I_{\text{max}}$ Spectral bandwidth at 50% of $I_{\text{max}}$ $I_F = 100 \text{ mA}$	$\Delta\lambda$	80	nm
Abstrahlwinkel Half angle	$\varphi$	± 60	Grad deg.
Aktive Chipfläche Active chip area	$A$	0.09	mm <sup>2</sup>
Abmessungen der aktiven Chipfläche Dimension of the active chip area	$L \times B$ $L \times W$	0.3 × 0.3	mm

Kennwerte ( $T_A = 25^\circ\text{C}$ )

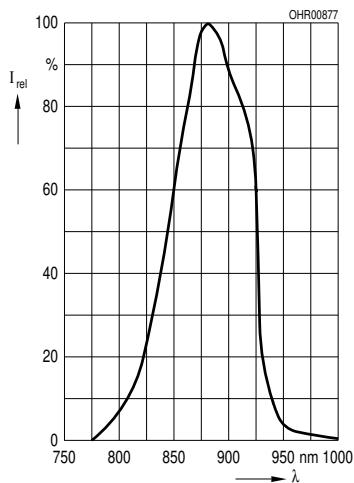
Characteristics (cont'd)

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Schaltzeiten, $I_e$ von 10% auf 90% und von 90% auf 10%, bei $I_F = 100 \text{ mA}$ , $R_L = 50 \Omega$ Switching times, $I_e$ from 10% to 90% and from 90% to 10%, $I_F = 100 \text{ mA}$ , $R_L = 50 \Omega$	$t_r, t_f$	0.5	$\mu\text{s}$
Kapazität, Capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_o$	15	pF
Durchlaßspannung, Forward voltage $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	$V_F$ $V_F$	1.5 ( $\leq 1.8$ ) 3.0 ( $\leq 3.8$ )	V V
Sperrstrom, Reverse current $V_R = 5 \text{ V}$	$I_R$	0.01 ( $\leq 1$ )	$\mu\text{A}$
Gesamtstrahlungsfluß, Total radiant flux $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$\Phi_e$	23	mW
Temperaturkoeffizient von $I_e$ bzw. $\Phi_e$ , $I_F = 100 \text{ mA}$ Temperature coefficient of $I_e$ or $\Phi_e$ , $I_F = 100 \text{ mA}$	$TC_I$	- 0.5	%/K
Temperaturkoeffizient von $V_F$ , $I_F = 100 \text{ mA}$ Temperature coefficient of $V_F$ , $I_F = 100 \text{ mA}$	$TC_V$	- 2	mV/K
Temperaturkoeffizient von $\lambda$ , $I_F = 100 \text{ mA}$ Temperature coefficient of $\lambda$ , $I_F = 100 \text{ mA}$	$TC_\lambda$	+ 0.25	nm/K

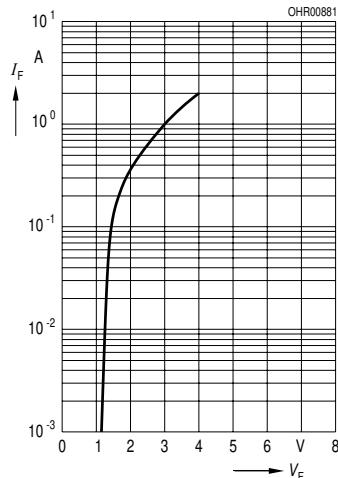
**Strahlstärke  $I_e$  in Achsrichtung**gemessen bei einem Raumwinkel  $\Omega = 0.01 \text{ sr}$ **Radiant Intensity  $I_e$  in Axial Direction**at a solid angle of  $\Omega = 0.01 \text{ sr}$ 

Bezeichnung Parameter	Symbol	Werte Values		Einheit Unit
		-P	-Q	
Strahlstärke Radiant intensity $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$I_{e \min}$ $I_{e \max}$	4 8	6.3 12.5	mW/sr mW/sr
Strahlstärke Radiant intensity $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	$I_{e \text{ typ.}}$	50	60	mW/sr

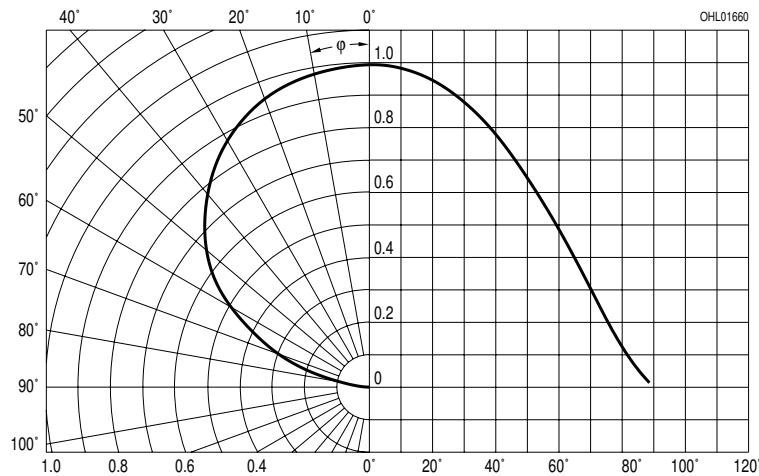
**Relative Spectral Emission**  
 $I_{\text{rel}} = f(\lambda)$



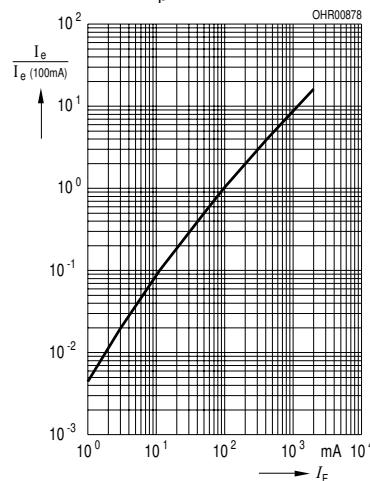
**Forward Current**  
 $I_F = f(V_F)$ , single pulse,  $t_p = 20 \mu\text{s}$



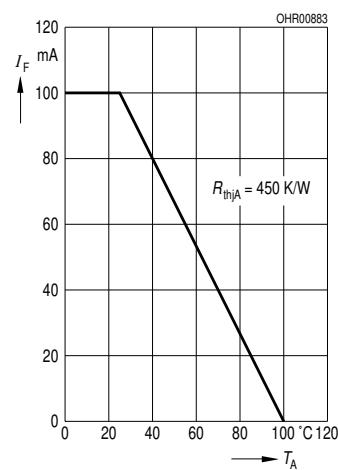
**Radiation Characteristics**  
 $S_{\text{rel}} = f(\phi)$



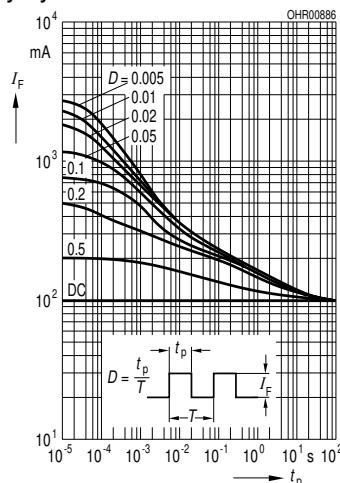
**Radiant Intensity**  $\frac{I_e}{I_e 100 \text{ mA}} = f(I_F)$   
Single pulse,  $t_p = 20 \mu\text{s}$

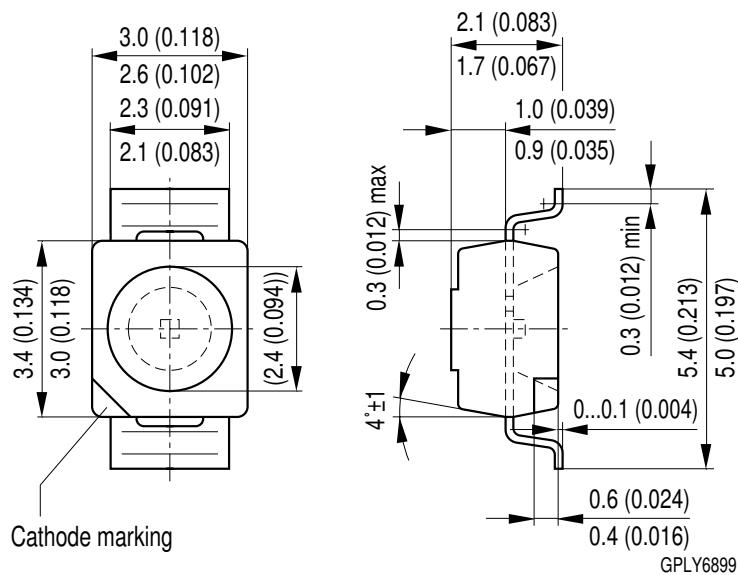


**Max. Permissible Forward Current**  
 $I_F = f(T_A)$



**Permissible Pulse Handling Capability**  $I_F = f(t_p)$ ,  $T_A = 25^\circ\text{C}$   
duty cycle  $D = \text{Parameter}$



**Maßzeichnung  
Package Outlines**

Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

**Löthinweise**  
**Soldering Conditions**

<b>Bauform</b> <b>Types</b>	<b>Tauch-, Schwall- und Schlepplötzung</b> <b>Dip, Wave and Drag Soldering</b>			<b>Reflowlötzung</b> <b>Reflow Soldering</b>	
	<b>Lötbad-temperatur</b> <b>Temperature of the Soldering Bath</b>	<b>Maximal zulässige Lötzeit</b> <b>Max. Perm. Soldering Time</b>	<b>Abstand Lötstelle – Gehäuse</b> <b>Distance between Solder Joint and Case</b>	<b>Lötzonen-temperatur</b> <b>Temperature of Soldering Zone</b>	<b>Maximale Durchlaufzeit</b> <b>Max. Transit Time</b>
TOPLED RG	260 °C	10 s	–	245 °C	10 s

Zusätzliche Informationen über allgemeine Lötbedingungen erhalten Sie auf Anfrage.

For additional information on general soldering conditions please contact us.

Published by OSRAM Opto Semiconductors GmbH & Co. OHG  
Wernerwerkstrasse 2, D-93049 Regensburg

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**Attention please!**

The information describes the type of component and shall not be considered as assured characteristics.  
Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances. For information on the types in question please contact our Sales Organization.

**Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

**Components used in life-support devices or systems must be expressly authorized for such purpose!** Critical components<sup>1</sup>, may only be used in life-support devices or systems<sup>2</sup> with the express written approval of OSRAM OS.

<sup>1</sup> A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or effectiveness of that device or system.

<sup>2</sup> Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.